

S22MD2

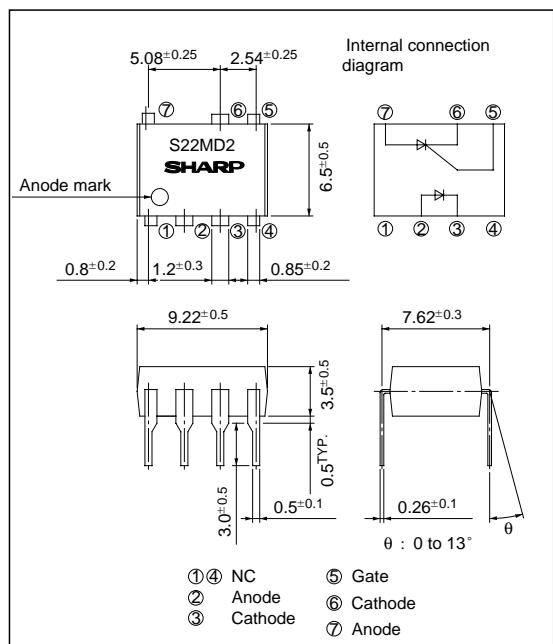
Phototyristor Coupler

■ Features

1. Long distance between anode and cathode of phototyristor on the output side : 5.08mm
 2. High repetitive peak OFF-state voltage (V_{DRM} : MIN. 600V)
 3. Low trigger current (I_{FT} : MAX. 8mA at $R_G = 20k\Omega$)
 4. High isolation voltage between input and output (V_{iso} : 5 000V_{rms})
- * S22MD2 is for 200V line.

■ Outline Dimensions

(Unit : mm)



■ Applications

1. ON-OFF operation for a low power load
2. For triggering high power thyristor and triac

■ Absolute Maximum Ratings

(Ta = 25°C)

	Parameter	Symbol	Rating	Unit
Input	Forward current	I_F	50	mA
	Reverse voltage	V_R	6	V
Output	RMS ON-state current	I_T	200	mA _{rms}
	^{*1} Peak one cycle surge current	I_{surge}	2	A
	^{*2} Repetitive peak OFF-state voltage	V_{DRM}	600	V
	^{*2} Repetitive peak reverse voltage	V_{RRM}	600	V
	^{*3} Isolation voltage	V_{iso}	5 000	V _{rms}
Operating temperature		T_{opr}	- 30 to + 100	°C
Storage temperature		T_{stg}	- 40 to + 125	°C
^{*4} Soldering temperature		T_{sol}	260	°C

*1 50Hz, sine wave

*2 $R_G = 20k\Omega$

*3 40 to 60% RH, AC for 1 minute

*4 For 10 seconds

■ Electro-optical Characteristics

(Ta = 25°C)

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input	Forward voltage	V _F	I _F = 30mA	-	1.2	1.4	V
	Reverse current	I _R	V _R = 4V	-	-	10 ⁻⁵	A
Output	Repetitive peak OFF-state current	I _{DRM}	V _{DRM} = Rated, R _G = 20kΩ	-	-	10 ⁻⁶	A
	Repetitive peak reverse current	I _{RRM}	V _{RRM} = Rated, R _G = 20kΩ	-	-	10 ⁻⁶	A
	ON-state voltage	V _T	I _T = 200mA	-	1.0	1.4	V
	Holding current	I _H	V _D = 6V, R _G = 20kΩ	-	0.3	1	mA
	Critical rate of rise of OFF-state voltage	dV/dt	V _{DRM} = 1/√2 Rated, R _G = 20kΩ	3	-	-	V/μs
Transfer-characteristics	Minimum trigger current	I _{FT}	V _D = 6V, R _L = 100Ω, R _G = 20kΩ	-	6	8	mA
	Isolation resistance	R _{ISO}	DC500V, 40 to 60% RH	5x 10 ¹⁰	10 ¹¹	-	Ω
	Turn-on time	t _{on}	V _D = 6V, R _G = 20kΩ, R _L = 100Ω, I _F = 30mA	-	20	50	μs

Fig. 1 RMS ON-state Current vs. Ambient Temperature

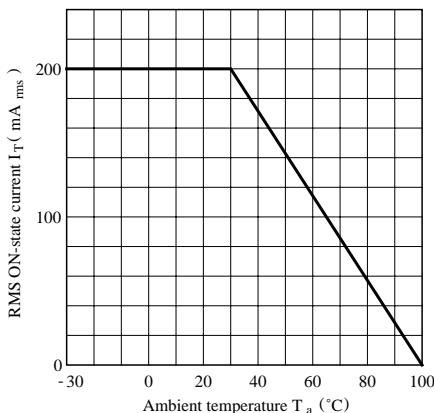


Fig. 2 Forward Current vs. Ambient Temperature

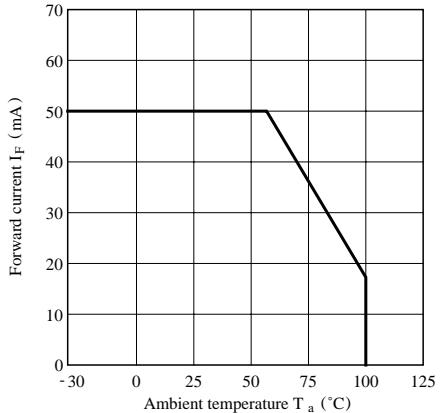


Fig. 3 Forward Current vs. Forward Voltage

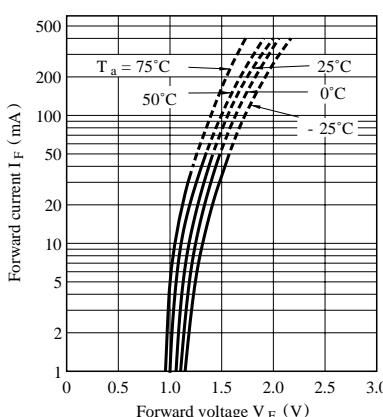


Fig. 4 Minimum Trigger Current vs. Ambient Temperature

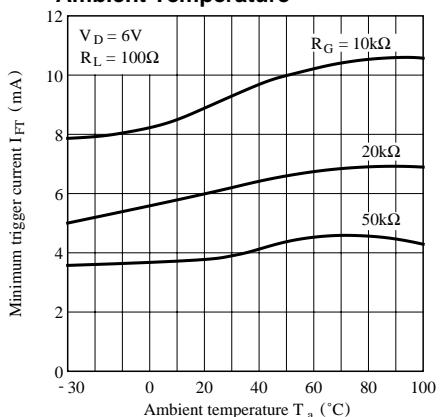


Fig. 5 Minimum Trigger Current vs. Gate Resistance

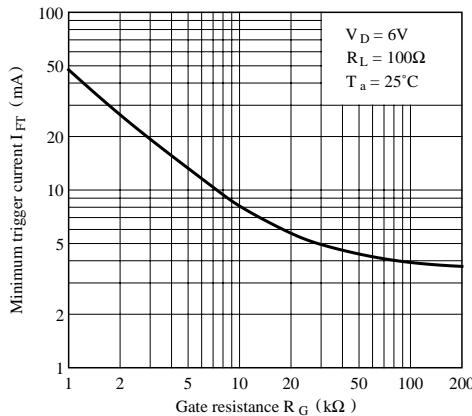


Fig. 6 Break Over Voltage vs. Ambient Temperature

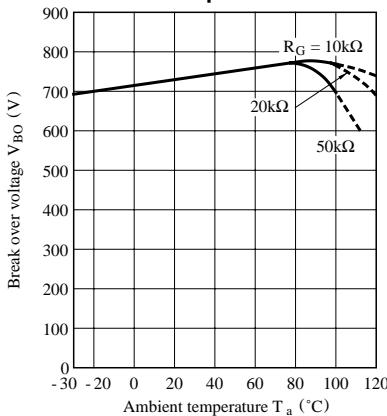


Fig. 7 Critical Rate of Rise of OFF-state Voltage vs. Ambient Temperature

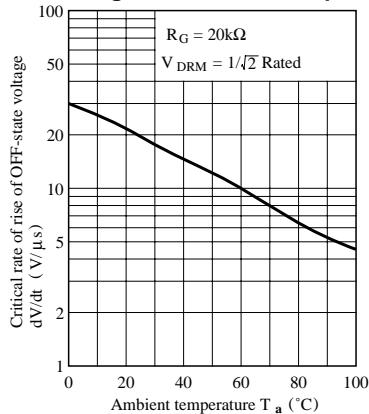


Fig. 8 Holding Current vs. Ambient Temperature

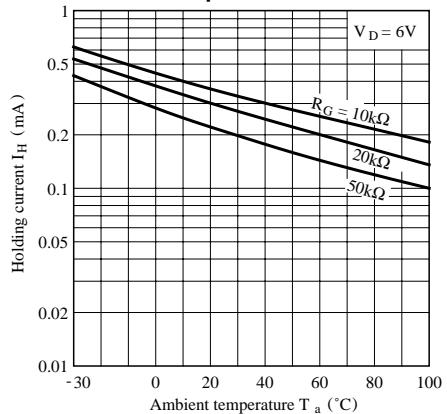
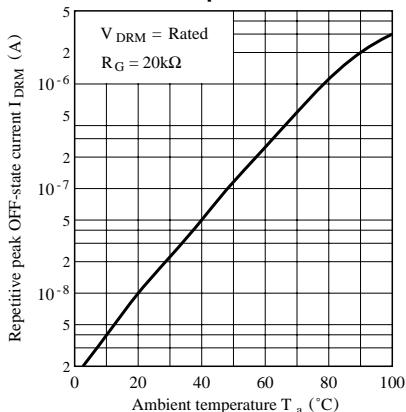
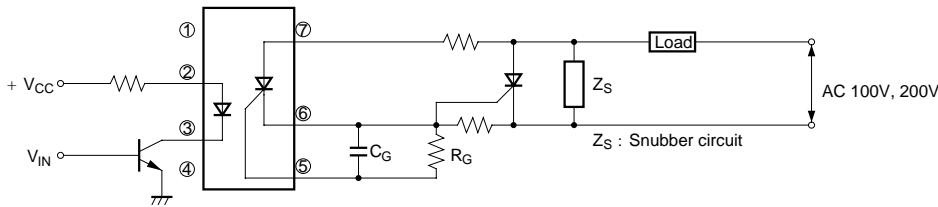


Fig. 9 Repetitive Peak OFF-state Current vs. Ambient Temperature

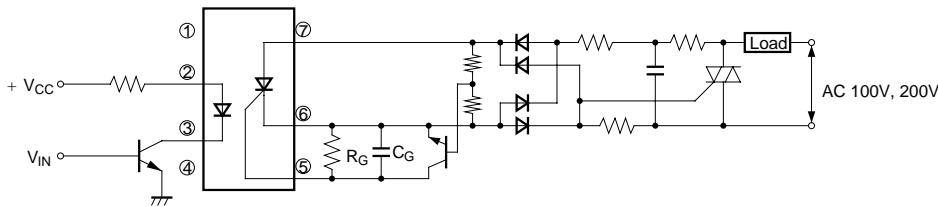


■ Basic Operation Circuit

Medium/High Power Thyristor Drive Circuit



Medium/High Power Triac Drive Circuit (Zero-cross Operation)



- Please refer to the chapter “Precautions for Use” (Page 78 to 93).